

# STTH108

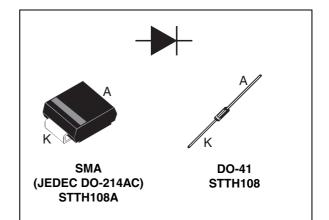
## High voltage ultrafast rectifier

### Features

- Low forward voltage drop
- High reliability
- High surge current capability
- Soft switching for reduced EMI disturbances
- Planar technology

### Description

The STTH108, which is using ST ultrafast high voltage planar technology, is specially suited for free-wheeling, clamping, snubbering, demagnetization in power supplies and other power switching applications.



### Table 1. Device summary

Symbol	Value			
I <sub>F(AV)</sub>	1 A			
V <sub>RRM</sub>	800 V			
T <sub>j</sub> (max)	175 °C			
V <sub>F</sub> (max)	1.25 V			

www.st.com

## 1 Characteristics

Table 2.	Absolute ratings (limiting values)

Symbol	Parameter			Value	Unit	
V <sub>RRM</sub>	Repetitive peak reverse vol	tage			800	V
V <sub>(RMS)</sub>	Voltage rms				560	V
	Average forward ourrent	SMA	T <sub>L</sub> = 110 °C	$\delta = 0.5$	1	А
IF(AV)	Average forward current	DO-41	T <sub>L</sub> = 130 °C	$\delta = 0.5$	I	А
	Forward Surga ourrant	SMA		SMA	20	А
IFSM	Forward Surge current t = 8.3 ms		DO-41	25	A	
T <sub>stg</sub>	Storage temperature range			-50 to + 175	°C	
Тj	Maximum operating junction temperature				175	°C

### Table 3. Thermal resistance

Symbol		Parameter			
D	Junction to lead		SMA	30	
R <sub>th(j-l)</sub>	Junction to lead	Lead length = 10 mm	DO-41	45	°C/W
R <sub>th(j-a)</sub>	Junction to ambient	Lead length = 10 mm	DO-41	110	

### Table 4. Static electrical characteristics

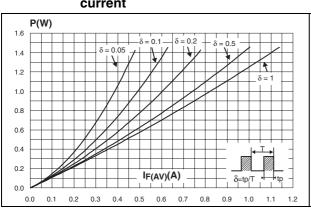
Symbol	Parameter	Tests conditions		Min.	Тур.	Max.	Unit
	Reverse leakage	T <sub>j</sub> = 25 °C	V <sub>B</sub> = 800 V			5	μA
<sup>I</sup> R	current	$T_j = 125 \text{ °C}$ $V_R = 0$	v <sub>R</sub> – 000 v		1	50	μΑ
V <sub>F</sub>	Earward voltage drop	$T_j = 25 \text{ °C}$				1.65	V
۴F	Forward voltage drop	T <sub>j</sub> = 125 °C	I <sub>F</sub> = 1 A		0.89	1.25	V

To evaluate the conduction losses use the following equation: P = 1.05 x  $I_{F(AV)}$  + 0.20  $I_{F}{}^{2}_{(RMS)}$ 

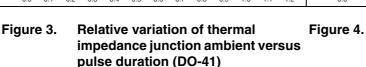
### Table 5. Dynamic electrical characteristics

Symbol	Parameter	Tests conditions		Min.	Тур.	Max.	Unit
t <sub>rr</sub>	Reverse recovery time	T <sub>j</sub> = 25 °C	$I_{F} = 0.5 \text{ A},$ $I_{rr} = 0.25 \text{ A}$ $I_{R} = 1 \text{ A}$			75	ns
t <sub>fr</sub>	Forward recovery time	T <sub>j</sub> = 25 °C	$\label{eq:IF} \begin{array}{l} I_F = 1 \text{ A}, \\ dI_F/dt = 50 \text{ A/ms} \\ V_{FR} = 1.1 \text{ x } V_F \text{max} \end{array}$			200	ns
V <sub>FP</sub>	Forward recovery voltage	T <sub>j</sub> = 25 °C	I <sub>F</sub> = 1 A, dI <sub>F</sub> /dt = 50 A/ms			12	V

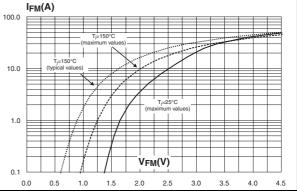




# Figure 1. Conduction losses versus average Figure 2. Forward current forward



. Forward voltage drop versus forward current



Relative variation of thermal impedance junction ambient versus pulse duration (epoxy FR4) (SMA)

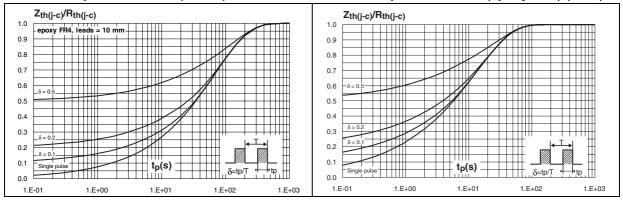
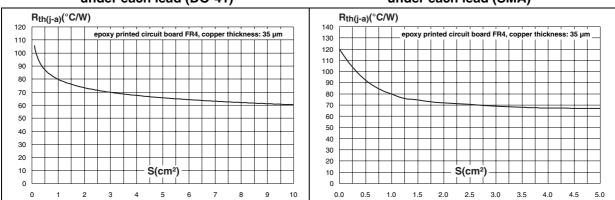


Figure 5. Thermal resistance junction to ambient versus copper surface under each lead (DO-41)

Figure 6. Thermal resistance junction to ambient versus copper surface under each lead (SMA)





## 2 Package information

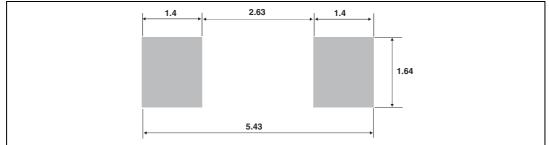
- Epoxy meets UL 94, V0
- Band indicates cathode
- Bending method (DO-41): see Application note AN1471

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK<sup>®</sup> packages, depending on their level of environmental compliance. ECOPACK<sup>®</sup> specifications, grade definitions and product status are available at: <u>www.st.com</u>. ECOPACK<sup>®</sup> is an ST trademark.

Table 6. SMA dimensions



Figure 7. Footprint (dimensions in mm)



### Table 7. DO-41 (plastic) package dimensions

		Dimer	nsions	
 Ref.	Millim	neters	Inc	hes
	Min.	Max.	Min.	Max.
Α	4.07	5.20	0.160	0.205
В	2.04	2.71	0.080	0.107
С	25.4		1	
D	0.71	0.86	0.028	0.034

Doc ID 9342 Rev 3



# **3** Ordering information

### Table 8. Ordering information

Order code	Marking	Package	Weight	Base qty	Delivery mode
STTH108	STTH108	DO-41	0.34 g	2000	Ammopack
STTH108A	H08	SMA	0.068 g	5000	Tape and reel
STTH108RL	STTH108	DO-41	0.34 g	5000	Tape and reel

## 4 Revision history

### Table 9. Document revision history

Date	Revision	Changes	
Jan-2003	2	Last update.	
30-Sep-2009	3	Updated table 7 package dimensions.	



#### Please Read Carefully:

Information in this document is provided solely in connection with ST products. STMicroelectronics NV and its subsidiaries ("ST") reserve the right to make changes, corrections, modifications or improvements, to this document, and the products and services described herein at any time, without notice.

All ST products are sold pursuant to ST's terms and conditions of sale.

Purchasers are solely responsible for the choice, selection and use of the ST products and services described herein, and ST assumes no liability whatsoever relating to the choice, selection or use of the ST products and services described herein.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted under this document. If any part of this document refers to any third party products or services it shall not be deemed a license grant by ST for the use of such third party products or services, or any intellectual property contained therein or considered as a warranty covering the use in any manner whatsoever of such third party products or services or any intellectual property contained therein.

UNLESS OTHERWISE SET FORTH IN ST'S TERMS AND CONDITIONS OF SALE ST DISCLAIMS ANY EXPRESS OR IMPLIED WARRANTY WITH RESPECT TO THE USE AND/OR SALE OF ST PRODUCTS INCLUDING WITHOUT LIMITATION IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION), OR INFRINGEMENT OF ANY PATENT, COPYRIGHT OR OTHER INTELLECTUAL PROPERTY RIGHT.

UNLESS EXPRESSLY APPROVED IN WRITING BY AN AUTHORIZED ST REPRESENTATIVE, ST PRODUCTS ARE NOT RECOMMENDED, AUTHORIZED OR WARRANTED FOR USE IN MILITARY, AIR CRAFT, SPACE, LIFE SAVING, OR LIFE SUSTAINING APPLICATIONS, NOR IN PRODUCTS OR SYSTEMS WHERE FAILURE OR MALFUNCTION MAY RESULT IN PERSONAL INJURY, DEATH, OR SEVERE PROPERTY OR ENVIRONMENTAL DAMAGE. ST PRODUCTS WHICH ARE NOT SPECIFIED AS "AUTOMOTIVE GRADE" MAY ONLY BE USED IN AUTOMOTIVE APPLICATIONS AT USER'S OWN RISK.

Resale of ST products with provisions different from the statements and/or technical features set forth in this document shall immediately void any warranty granted by ST for the ST product or service described herein and shall not create or extend in any manner whatsoever, any liability of ST.

ST and the ST logo are trademarks or registered trademarks of ST in various countries.

Information in this document supersedes and replaces all information previously supplied.

The ST logo is a registered trademark of STMicroelectronics. All other names are the property of their respective owners.

© 2009 STMicroelectronics - All rights reserved

STMicroelectronics group of companies

Australia - Belgium - Brazil - Canada - China - Czech Republic - Finland - France - Germany - Hong Kong - India - Israel - Italy - Japan -Malaysia - Malta - Morocco - Philippines - Singapore - Spain - Sweden - Switzerland - United Kingdom - United States of America

www.st.com

Doc ID 9342 Rev 3



单击下面可查看定价,库存,交付和生命周期等信息

>>STMicro(意法半导体)